## HI-201HS/883

### High Speed Quad SPST CMOS Analog Switch
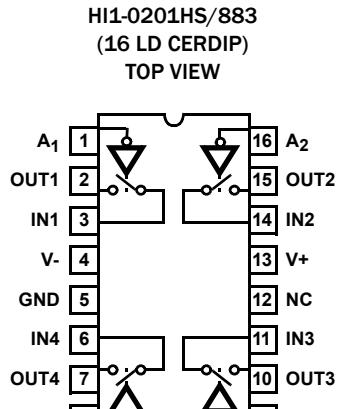
The HI-201HS/883 is a monolithic CMOS analog switch featuring very fast switching speeds and low ON resistance. This integrated circuit consists of four independently selectable SPST switches and is pin compatible with the industry standard HI-201 switch.

Fabricated using silicon-gate technology and the Intersil dielectric isolation process, this TTL compatible device offers improved performance over previously available CMOS analog switches while eliminating the problem of latch-up associated with other fabrication processes. Featuring maximum switching times of 50ns, low ON resistance of 50Ω maximum, and a wide analog signal range, the HI-201HS/883 is designed for any military application where improved switching performance, particularly switching speed, is required. (A more detailed discussion on the design and application of the HI-201HS/883 can be found in Application Note AN543.)

The HI-201HS/883 is available in a 16 Ld CerDIP package and is specified over the temperature range of -55°C to +125°C.

## Features

- This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.
- Low "On" Release . . . . . . . . . . . . . . . . . . . . . . . . . . . . 50Ω Max
- Wide Analog Signal Range . . . . . . . . . . . . . . . . . . . . . . . . ±15V
- Turn-On Time. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 50ns
- Analog Current Range (Continuous) . . . . . . . . . . . . . . 25mA
- TTL/CMOS Compatible
- No Latch-Up
- Pin Compatible with Standard HI-201

## Applications

- High Speed Multiplexing
- High Frequency Analog Switching
- Sample and Hold Circuits
- Digital Filters
- Op Amp Gain Switching Networks
- Integrator Reset Circuits

## Pin Configuration



HI1-0201HS/883
(16 LD CERDIP)
TOP VIEW

| A₁ | 1 | | 16 | A₂ |
| OUT1 | 2 | | 15 | OUT2 |
| IN1 | 3 | | 14 | IN2 |
| V- | 4 | | 13 | V+ |
| GND | 5 | | 12 | NC |
| IN4 | 6 | | 11 | IN3 |
| OUT4 | 7 | | 10 | OUT3 |
| A₄ | 8 | | 9 | A₃ |

### TRUTH TABLE

| LOGIC | SWITCH |
|-------|--------|
| 0 | ON |
| 1 | OFF |

## Functional Diagram



## Ordering Information

| PART NUMBER | PART MARKING | TEMP. RANGE (°C) | PACKAGE | PKG. DWG. # |
|-------------|--------------|------------------|---------|-------------|
| HI1-0201HS/883 | HI1-201HS/883 | -55 to +125 | 16 Ld CerDIP | F16.3 |

HI-201HS/883

## Absolute Maximum Ratings

Voltage Between V+ and V- Terminals . . . . . . . . . . . . . . . . . . . . . . . . . . . . 36V
$\pm V_{SUPPLY}$ to Ground (V+, V-) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm$18V
Analog Input Voltage, (+$V_S$). . . . . . . . . . . . . . . . . . . . . . . . . . . +$V_{SUPPLY}$ +2V
                     (-$V_S$) . . . . . . . . . . . . . . . . . . . . . . . . . . . . -$V_{SUPPLY}$ -2V
Digital Input Voltage, (+$V_A$) . . . . . . . . . . . . . . . . . . . . . . . . . . +$V_{SUPPLY}$ +4V
                 (-$V_A$). . . . . . . . . . . . . . . . . . . . . . . . . . . . -$V_{SUPPLY}$ -4V
Peak Current (S or D)
   (Pulse at 1ms, 10% Duty Cycle Max) . . . . . . . . . . . . . . . . . . . . . . . 50mA
Continuous Current Any Terminal (Except S or D) . . . . . . . . . . . . . . 25mA

## Thermal Information

Thermal Resistance               $\theta_{JA}$ (°C/W)    $\theta_{JC}$ (°C/W)
   CerDIP Package . . . . . . . . . . . . . . . . . . . . . . .    75        16
Package Power Dissipation at +75°C
   CerDIP Package . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 1.0W
Package Power Dissipation Derating Factor above +75°C
   CerDIP Package . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 13.36mW/°C
Junction Temperature . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . .+175°C
Storage Temperature Range. . . . . . . . . . . . . . . . . . . . . . . .-65°C to +150°C
Lead Temperature (Soldering 10s). . . . . . . . . . . . . . . . . . . . . . . . . .≤275°C

## Recommended Operating Conditions

Operating Temperature Range . . . . . . . . . . . . . . . . . . . . . . .-55°C to +125°C
Operating Supply Voltage Range ($\pm V_{SUPPLY}$) . . . . . . . . . . . . . . . . . . . .$\pm$15V
Analog Input Voltage ($V_S$) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . $\pm V_{SUPPLY}$
Logic Low Level ($V_{AL}$) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . .0V to 0.8V
Logic High Level ($V_{AH}$) . . . . . . . . . . . . . . . . . . . . . . . . . . . . . .3.0V to +$V_{SUPPLY}$

*CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.*

**TABLE 1. D.C. ELECTRICAL PERFORMANCE SPECIFICATIONS**

Device Tested at: +$V_{SUPPLY}$ = +15V, -$V_{SUPPLY}$ = -15V, GND = 0V, unless otherwise specified.

| D.C. PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE (°C) | MIN | MAX | UNITS |
|---|---|---|---|---|---|---|---|
| Switch "ON" Resistance | $r_{DS}$ | $V_A$ = 0.8V, $V_S$ = 10V, $I_D$ = -1mA All Unused Channels $V_{AL}$ = 0.8V | 1 | +25 | - | 50 | Ω |
| | | | 2, 3 | -55 to +125 | - | 75 | Ω |
| | | $V_A$ = 0.8V, $V_S$ = -10V, $I_D$ = 1mA All Unused Channels $V_{AL}$ = 0.8V | 1 | +25 | - | 50 | Ω |
| | | | 2, 3 | -55 to +125 | - | 75 | Ω |
| Source "OFF" Leakage Current | $I_{S(OFF)}$ | $V_S$ = +14V, $V_D$ = -14V, $V_{AH}$ = 3.0V All Unused Channels $V_{AH}$ = 3.0V, $V_D$ = +14V, $V_S$ = -14V | 1 | +25 | -10 | 10 | nA |
| | | | 2, 3 | -55 to +125 | -100 | 100 | nA |
| | | $V_S$ = -14V, $V_D$ = +14V, $V_{AH}$ = 3.0V All Unused Channels $V_{AH}$ = 3.0V, $V_D$ = -14V, $V_S$ = +14V | 1 | +25 | -10 | 10 | nA |
| | | | 2, 3 | -55 to +125 | -100 | 100 | nA |
| Drain "OFF" Leakage Current | $I_{D(OFF)}$ | $V_D$ = -14V, $V_S$ = +14V, $V_{AH}$ = 3.0V All Unused Channels $V_{AH}$ = 3.0V, $V_D$ = +14V, $V_S$ = -14V | 1 | +25 | -10 | 10 | nA |
| | | | 2, 3 | -55 to +125 | -100 | 100 | nA |
| | | $V_D$ = +14V, $V_S$ = -14V, $V_{AH}$ = 3.0V All Unused Channels $V_{AH}$ = 3.0V, $V_D$ = -14V, $V_S$ = +14V | 1 | +25 | -10 | 10 | nA |
| | | | 2, 3 | -55 to +125 | -100 | 100 | nA |
| Channel "ON" Leakage Current | $I_{D(ON)}$ | $V_D$ = $V_S$ = +14V, $V_{AL}$ = 0.8V, All Unused Channels $V_{AL}$ = 0.8V, $V_D$ = $V_S$ = -14V | 1 | +25 | -10 | 10 | nA |
| | | | 2, 3 | -55 to +125 | -100 | 100 | nA |
| | | $V_D$ = $V_S$ = -14V, $V_{AL}$ = 0.8V, All Unused Channels $V_{AL}$ = 0.8V, $V_D$ = $V_S$ = +14V | 1 | +25 | -10 | 10 | nA |
| | | | 2, 3 | -55 to +125 | -100 | 100 | nA |
| Low Level Input Current | $I_{AL}$ | $V_{AL}$ = 0.8V All Unused Channels $V_{AH}$ = 4.0V | 1 | +25 | - | 500 | µA |
| | | | 2, 3 | -55 to +125 | - | 500 | µA |
| High Level Input Current | $I_{AH}$ | $V_{AH}$ = 4.0V All Unused Channels $V_{AL}$ = 0.8V | 1 | +25 | - | 40 | µA |
| | | | 2, 3 | -55 to +125 | - | 40 | µA |
| Supply Current | +$I_{CC}$ | All Channels $V_{AL}$ = 0.8V | 1, 2 | +25, +125 | - | 10 | mA |
| | | | 3 | -55 | - | 10 | mA |
| | | All Channels $V_{AH}$ = 3.0V | 1, 2 | +25, +125 | - | 10 | mA |
| | | | 3 | -55 | - | 10 | mA |

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**TABLE 1. D.C. ELECTRICAL PERFORMANCE SPECIFICATIONS (Continued)**

Device Tested at: $+V_{SUPPLY} = +15V$, $-V_{SUPPLY} = -15V$, GND = 0V, unless otherwise specified.

| D.C. PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE (°C) | MIN | MAX | UNITS |
|---|---|---|---|---|---|---|---|
| Supply Current | $-I_{CC}$ | All Channels $V_{AL}$ = 0.8V | 1, 2 | +25, +125 | - | 6 | mA |
| | | | 3 | -55 | - | 6 | mA |
| | | All Channels $V_{AH}$ = 3.0V | 1, 2 | +25, +125 | - | 6 | mA |
| | | | 3 | -55 | - | 6 | mA |

**TABLE 2. A.C. ELECTRICAL PERFORMANCE SPECIFICATIONS**

Device Tested at: $+V_{SUPPLY} = +15V$, $-V_{SUPPLY} = -15V$, GND = 0V, unless otherwise specified.

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUPS | TEMPERATURE (°C) | MIN | MAX | UNITS |
|---|---|---|---|---|---|---|---|
| Turn "ON" Time | $t_{(ON)}$ | $C_L$ = 35pF, $R_L$ = 1kΩ $V_{AH}$ = 3.0V, $V_{AL}$ - 0.8V | 9 | +25 | - | 50 | ns |
| | | | 10, 11 | -55, +125 | - | 100 | ns |
| Turn "OFF" Time | $t_{(OFF)}$ | $C_L$ = 35pF, $R_L$ = 1kΩ $V_{AH}$ = 3.0V, $V_{AL}$ - 0.8V | 9 | +25 | - | 50 | ns |
| | | | 10, 11 | -55, +125 | - | 100 | ns |

**TABLE 3. ELECTRICAL PERFORMANCE SPECIFICATIONS (NOTE 1)**

Device Characterized at: $+V_{SUPPLY} = +15V$, $-V_{SUPPLY} = -15V$, GND = 0V

| PARAMETERS | SYMBOL | CONDITIONS | NOTE | TEMPERATURE (°C) | MIN | MAX | UNITS |
|---|---|---|---|---|---|---|---|
| Address Capacitance | $C_A$ | f = 1MHz, $V_{AL}$ = 0V | 1 | +25 | - | 35 | pF |
| Switch Input Capacitance | $C_{S\ (OFF)}$ | f = 1MHz, $V_{AH}$ = 5V, Measure Input to GND | 1 | +25 | - | 20 | pF |
| Switch Output Capacitance | $C_{D\ (OFF)}$ | f = 1MHz, $V_{AH}$ = 5V, Measure Output to Ground | 1 | +25 | - | 20 | pF |
| | $C_{D\ (ON)}$ | f = 1MHz, $V_{AL}$ = 0V, Measure Output to Ground | 1 | +25 | - | 50 | pF |
| Drain to Source Capacitance | $C_{DS}$ | f = 1MHz, $V_{AH}$ = 5V | 1 | +25 | - | 2.0 | pF |
| Off Isolation | $V_{ISO}$ | f = 100kHz, $V_A$ = 3.0, $R_L$ = 1k, $V_{GEN}$ = 1$V_{P-P}$, $C_L$ = 10pF | 1 | +25 | 50 | - | dB |
| Cross Talk | $V_{CT}$ | f = 100kHz, $V_A$ = 3.0, $R_L$ = 1k, $V_{GEN}$ = 1$V_{P-P}$, $C_L$ = 10pF | 1 | +25 | 50 | - | dB |
| Charge Transfer Error | $V_{CTE}$ | $R_L$ = 1k, $C_L$ = 0.01µF | 1 | +25 | - | 10 | mV |

NOTE:

1. Parameters listed in Table 3 are controlled via design or process parameters and are not directly tested at final production. These parameters are lab characterized upon initial design release, or upon design changes. These parameters are guaranteed by characterization based upon data from multiple production runs which reflect lot to lot and within lot variation.

**TABLE 4. ELECTRICAL TEST REQUIREMENTS**

| MIL-STD-883 TEST REQUIREMENTS | SUBGROUPS (Tables 1 and 2) |
|---|---|
| Interim Electrical Parameters (Pre Burn-in) | 1 |
| Final Electrical Test Parameters | 1 (Note 2), 2, 3, 9, 10, 11 |
| Group A Test Requirements | 1, 2, 3, 9, 10, 11 |
| Groups C & D Endpoints | 1 |

NOTE:

2. PDA applies to Subgroup 1 only.

# Test Circuits
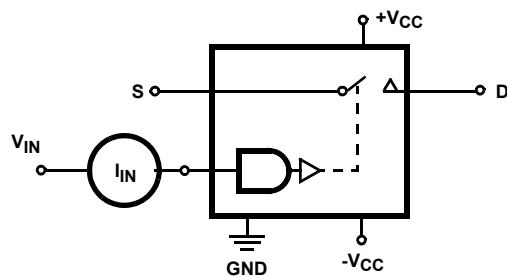


FIGURE 1.  INPUT LEAKAGE CURRENT
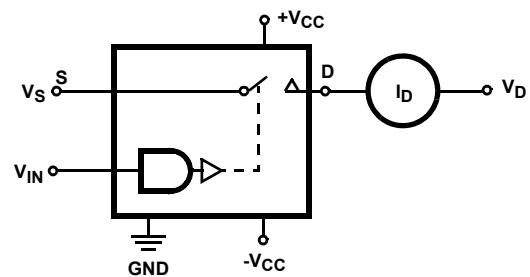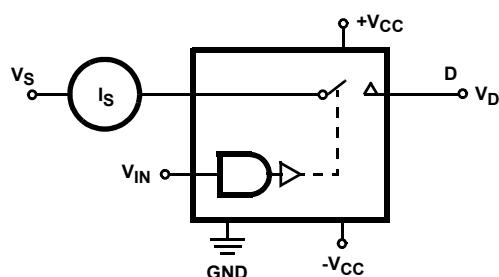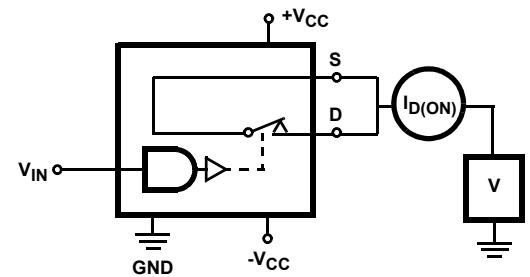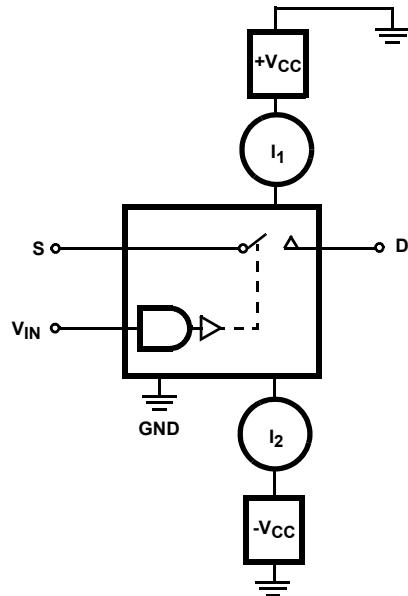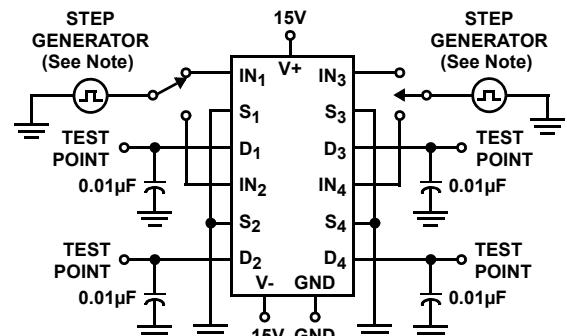


FIGURE 2.  $I_{D(OFF)}$



FIGURE 3.  $I_{S(OFF)}$



FIGURE 4.  $I_{D(ON)}$
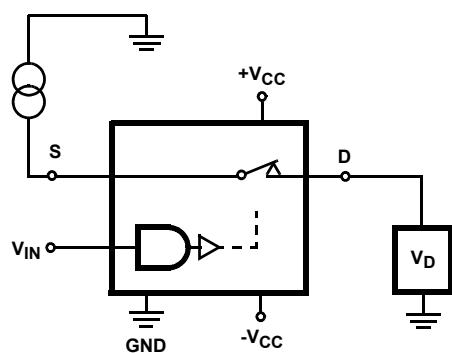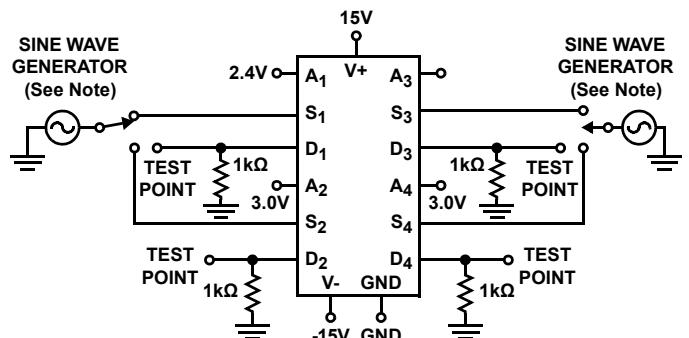


FIGURE 5.  SUPPLY CURRENTS



NOTE:  The pulse generator has the following characteristics:
$V_{GEN}$ = 0V to 3V, rise time ≤ 20ns, fall time ≤ 20ns, PRR = 100kHz.
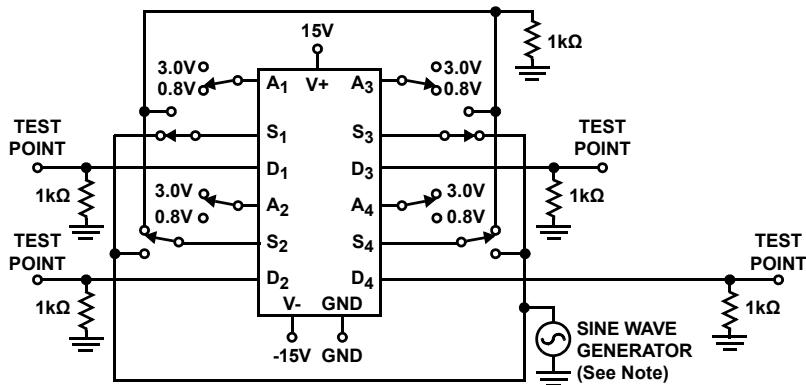
FIGURE 6.  CHARGE TRANSFER ERROR

# Test Circuits (Continued)



FIGURE 7. R$_{DS}$



NOTE: The pulse generator has the following characteristics: V$_{GEN}$ = 1V$_{P-P}$, Frequency = 100kHz.
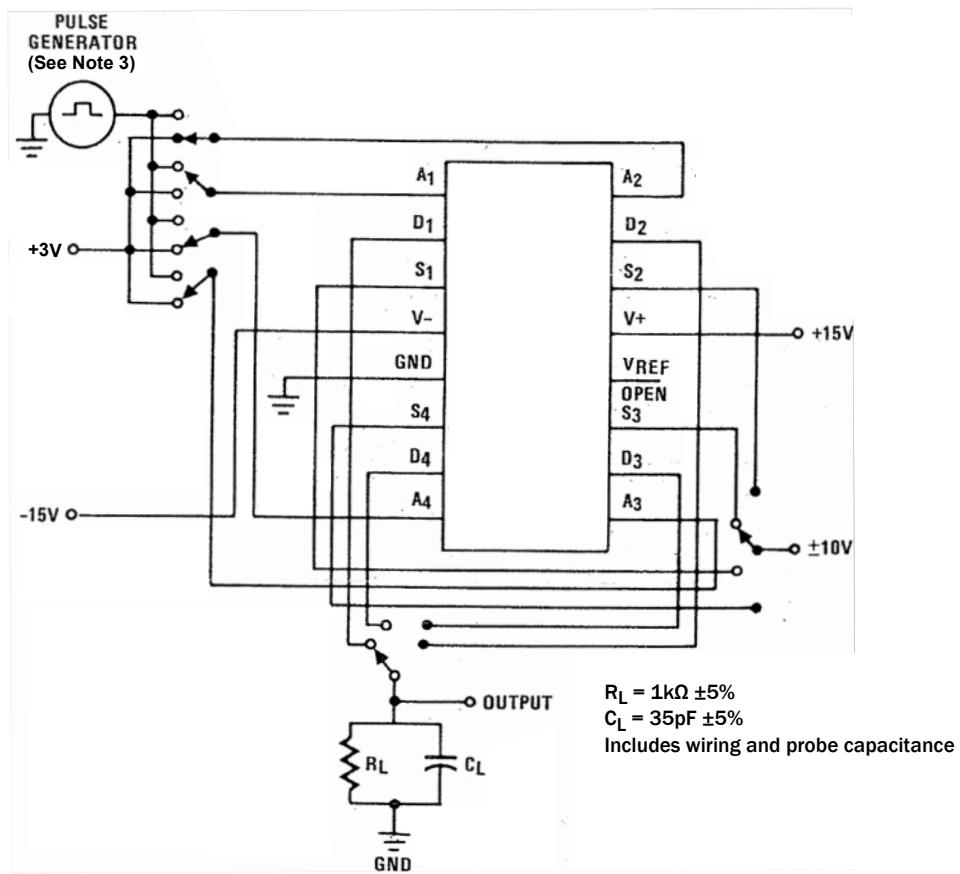
FIGURE 8. OFF CHANNEL ISOLATION



NOTE: The pulse generator has the following characteristics: V$_{GEN}$ = 1V$_{P-P}$, Frequency = 100kHz.
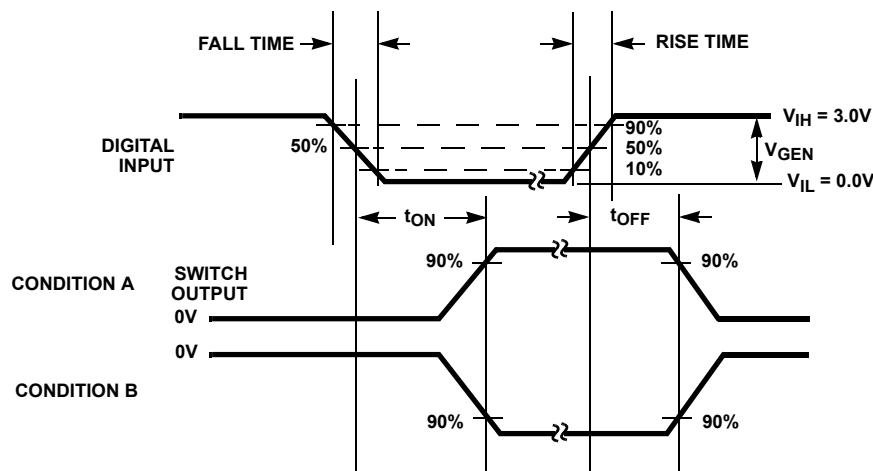
FIGURE 9. CROSSTALK BETWEEN CHANNELS

# Switching Waveforms



$R_L = 1k\Omega \pm 5\%$
$C_L = 35pF \pm 5\%$
Includes wiring and probe capacitance

NOTES:
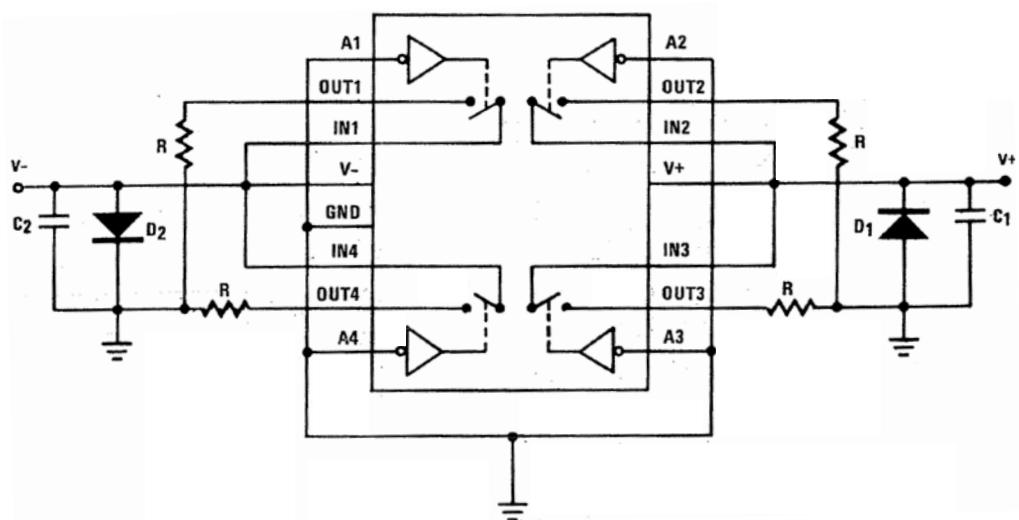
3. The pulse generator has the following characteristics:
   $V_{GEN} = 3.0V$, $t_{THL} \le 20ns$

4. See Table 2 for complete terminal conditions



NOTE: Rise time and fall time ≤20ns.

# Burn-In Circuit

**HI-201HS/883 CERDIP**



NOTE:
R = 10kΩ, 5%, 1/4W or 1/2W.
$C_1 = C_2$ = 0.01μF (per socket) or 0.1μF (per row).
$D_1 = D_2$ = IN4002 or equivalent (one per board).
|(V+) - (V-)| = 30V.
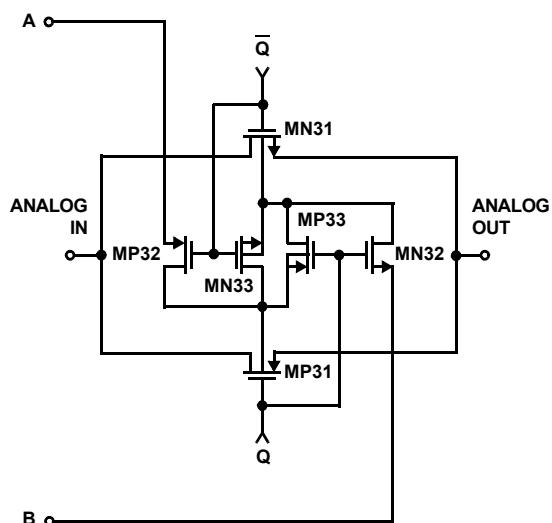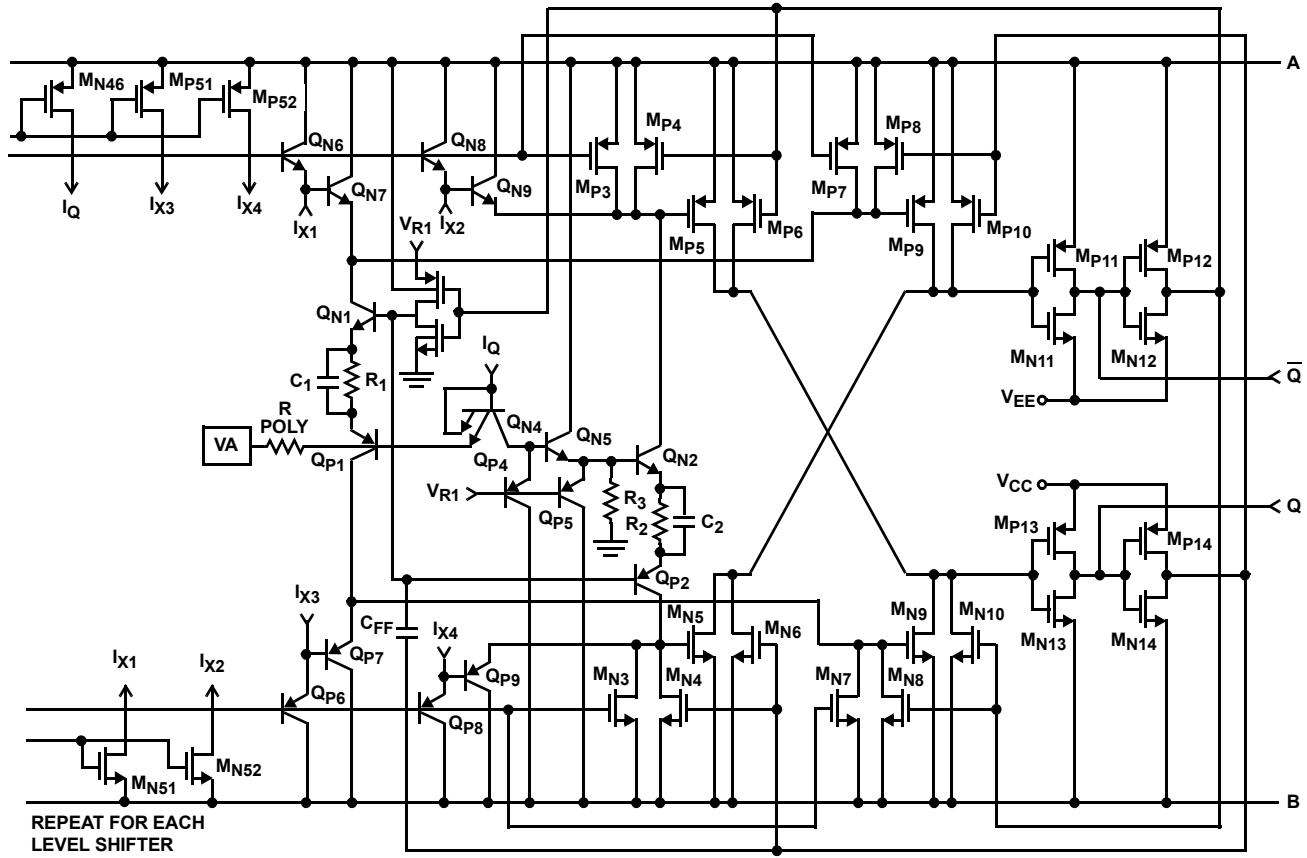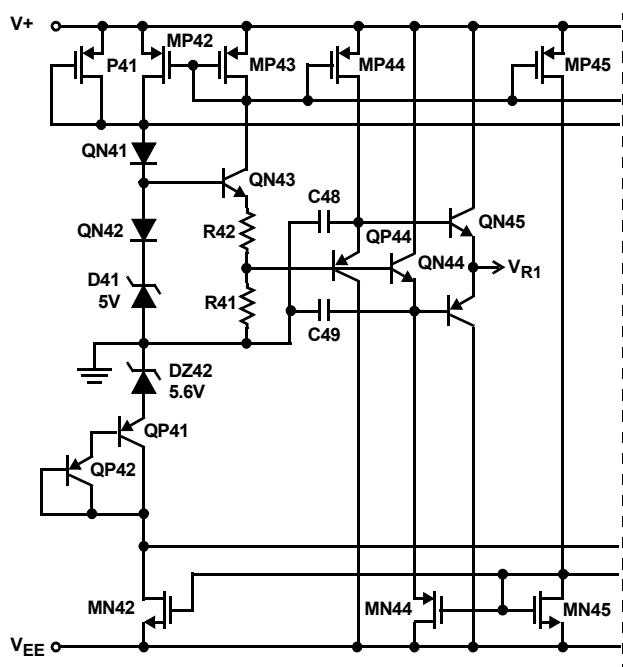
# Schematic Diagrams

**SWITCH CELL**

# Schematic Diagrams (Continued)

**REFERENCE/LEVEL SHIFTER**

# Die Characteristics

### DIE DIMENSIONS:

92mils x 111mils x 19mils

### METALLIZATION:

Type:  Aluminum
Thickness:  16kÅ $\pm$2kÅ

### GLASSIVATION:

Type: Nitride
Nitride Thickness:  7kÅ $\pm$0.7kÅ
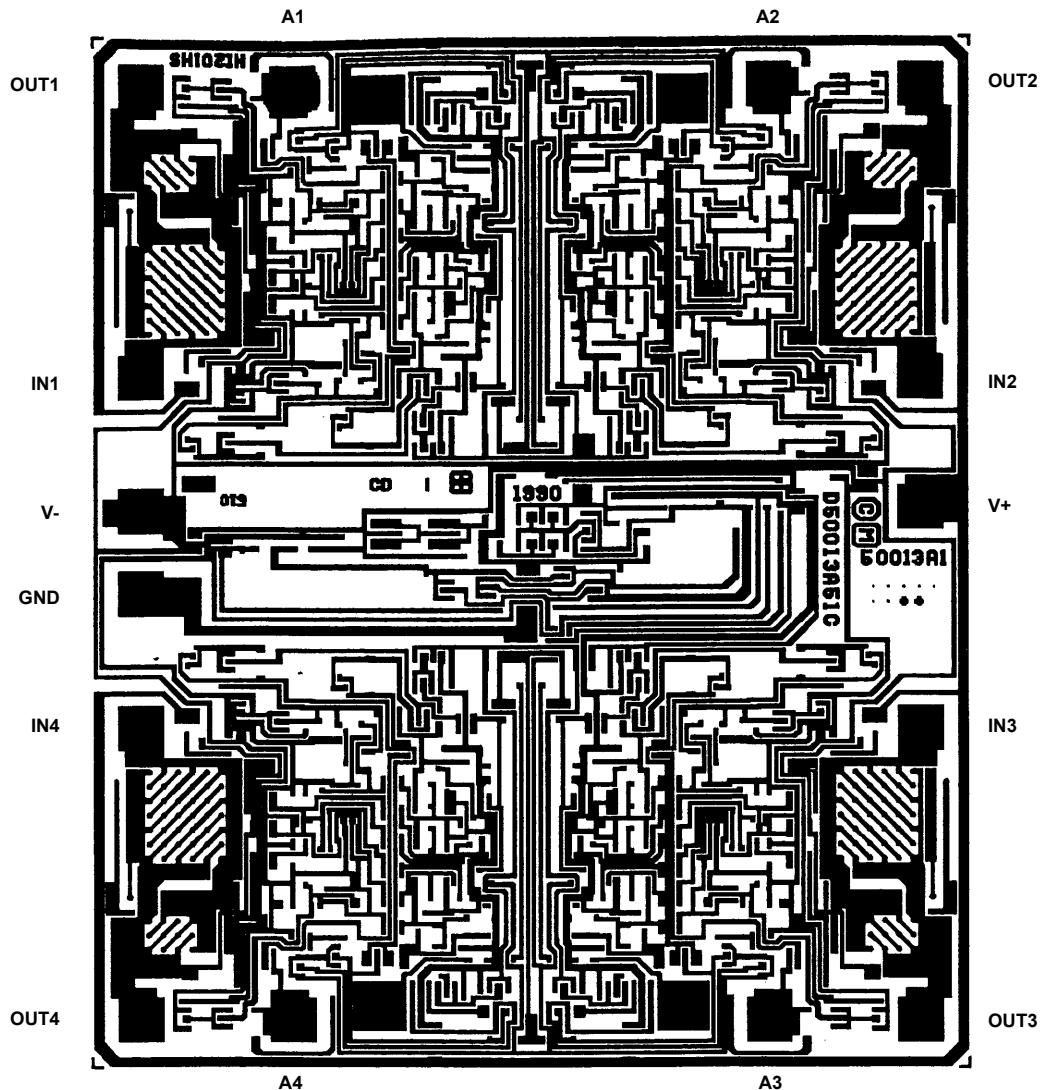
### WORST CASE CURRENT DENSITY:

$4.5 \times 10^5 A/cm^2$ at 25mA

This device meets Glassivation Integrity Test requirement per Mil-Std-883 Method 2021 and Mil-M-38510 paragraph 3.5.5.4.

# Metallization Mask Layout

HI-201HS/883

*The information contained in this section has been developed through characterization and is for use as application and design information only. No guarantee is implied.*

# Typical Performance Curves $T_A$ = +25°C, $V_{SUPPLY}$ = ±15V, $V_{AH}$ = 3.0V, $V_{AL}$ = 0.8V
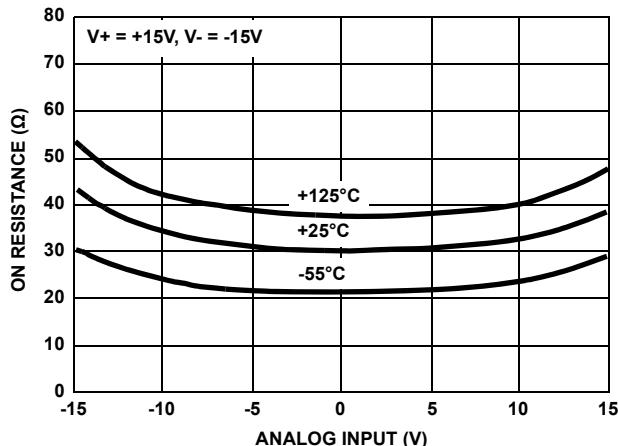
FIGURE 10. ON RESISTANCE vs ANALOG SIGNAL LEVEL AND TEMPERATURE
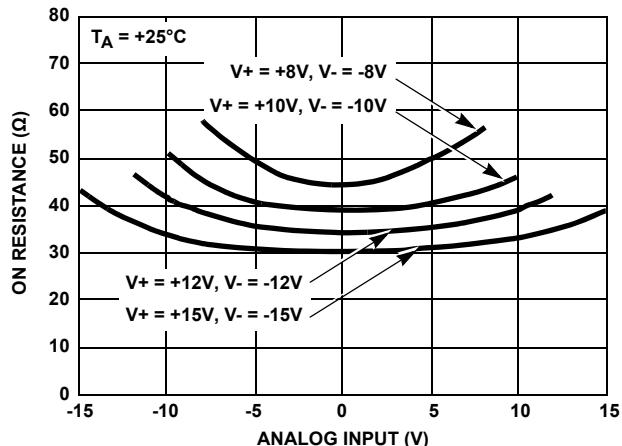
FIGURE 11. ON RESISTANCE vs ANALOG SIGNAL LEVEL AND POWER SUPPLY VOLTAGE
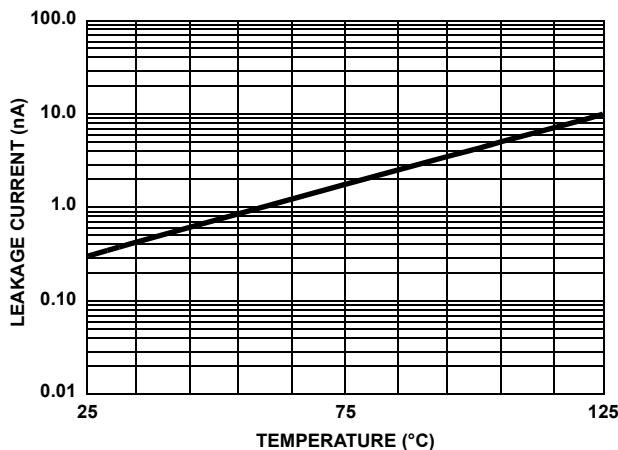
FIGURE 12. $I_{S(OFF)}$ OR $I_{D(OFF)}$ vs TEMPERATURE
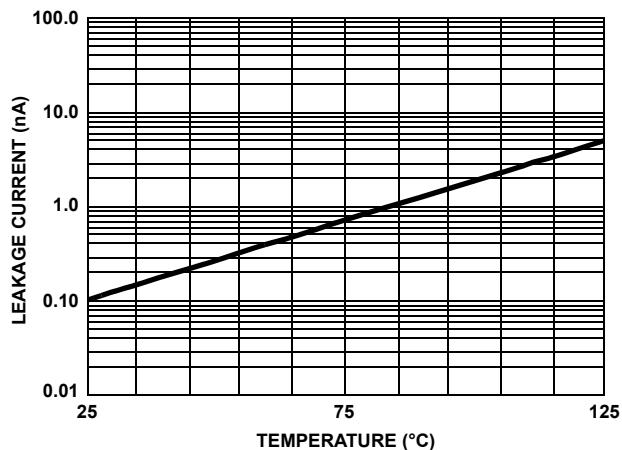
FIGURE 13. $I_{D(ON)}$ vs TEMPERATURE
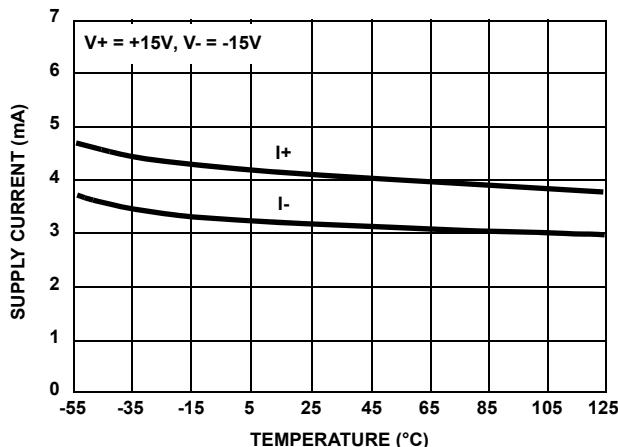
FIGURE 14. SUPPLY CURRENT vs TEMPERATURE
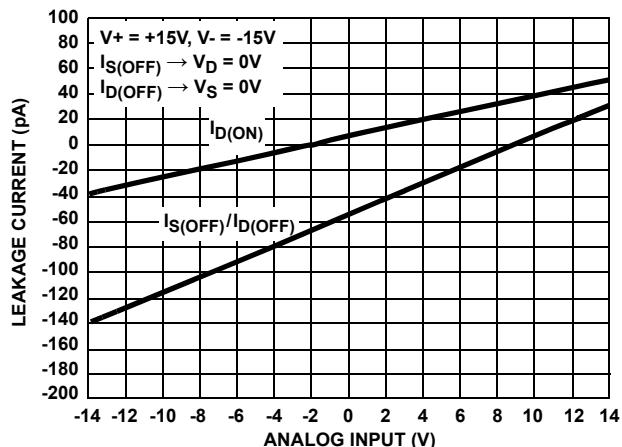
FIGURE 15. LEAKAGE CURRENT vs ANALOG INPUT VOLTAGE

*The information contained in this section has been developed through characterization and is for use as application and design information only. No guarantee is implied.*

# Typical Performance Curves $T_A$ = +25°C, $V_{SUPPLY}$ = ±15V, $V_{AH}$ = 3.0V, $V_{AL}$ = 0.8V **(Continued)**
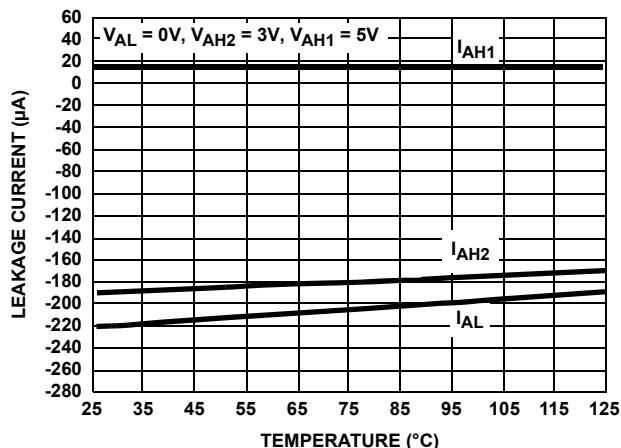


FIGURE 16. DIGITAL INPUT LEAKAGE CURRENT vs TEMPERATURE
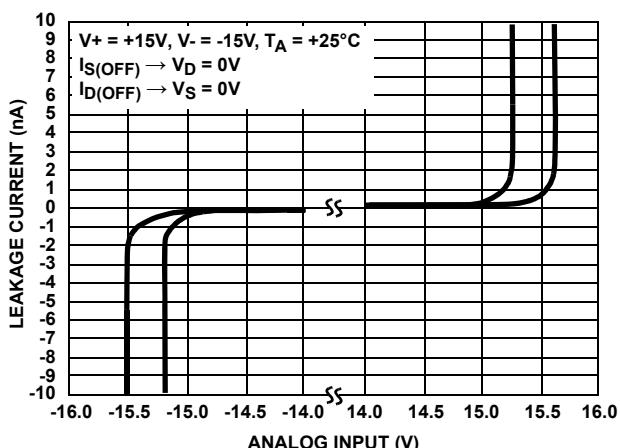


FIGURE 17. LEAKAGE CURRENT vs ANALOG INPUT VOLTAGE
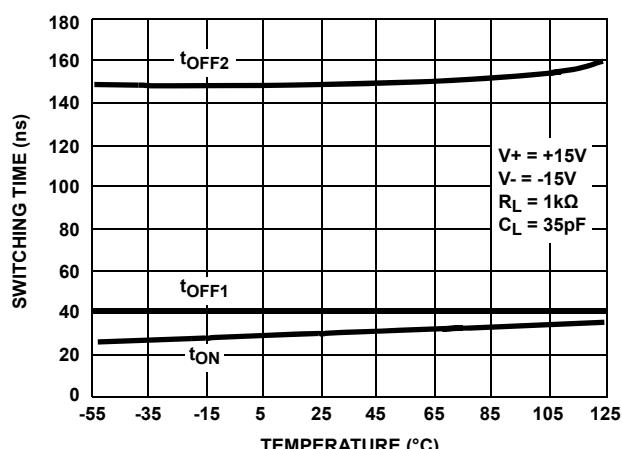


FIGURE 18. SWITCHING TIME vs TEMPERATURE
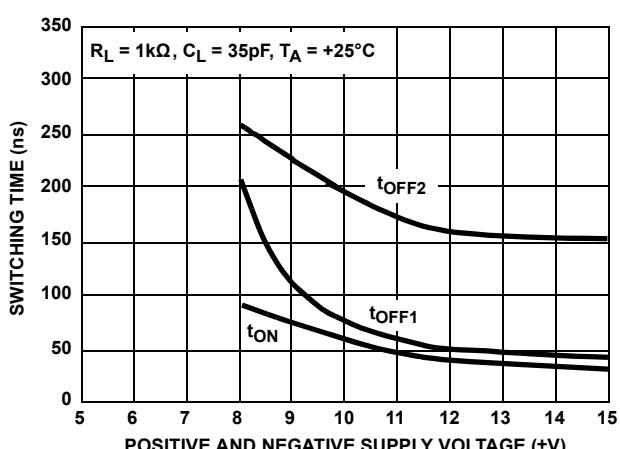


FIGURE 19. SWITCHING TIME vs POSITIVE AND NEGATIVE SUPPLY VOLTAGE
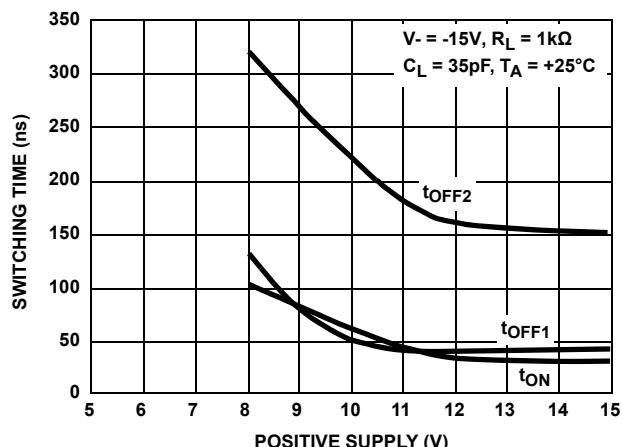


FIGURE 20. SWITCHING TIME vs POSITIVE SUPPLY VOLTAGE
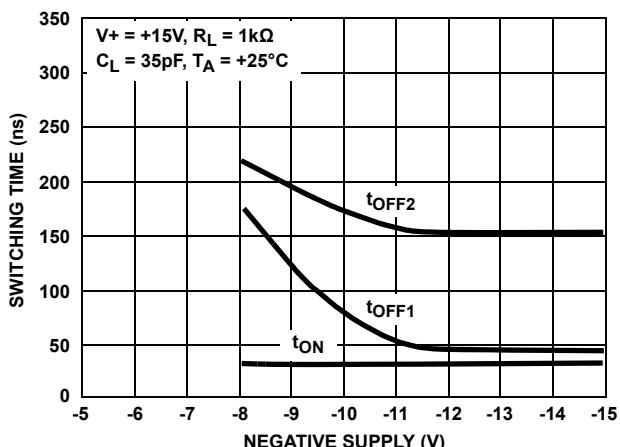


FIGURE 21. SWITCHING TIME vs NEGATIVE SUPPLY VOLTAGE

*The information contained in this section has been developed through characterization and is for use as application and design information only. No guarantee is implied.*

# Typical Performance Curves $T_A$ = +25°C, $V_{SUPPLY}$ = ±15V, $V_{AH}$ = 3.0V, $V_{AL}$ = 0.8V (Continued)
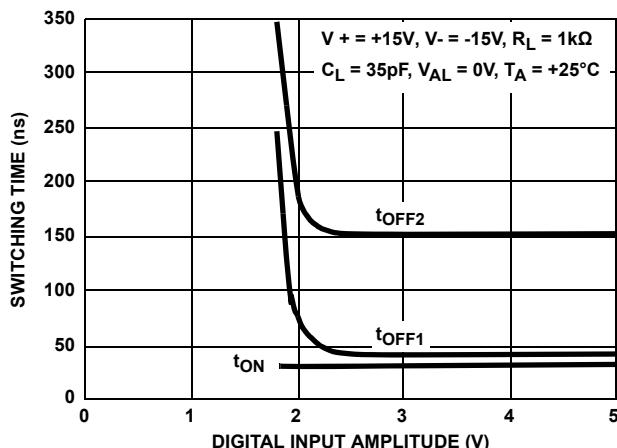


FIGURE 22. SWITCHING TIME vs INPUT LOGIC AMPLITUDE
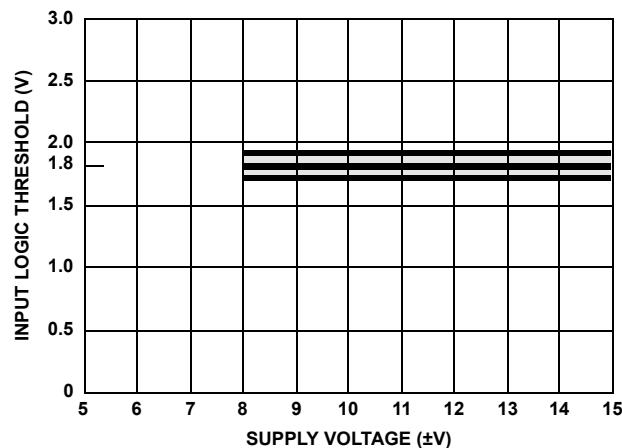


FIGURE 23. INPUT SWITCHING THRESHOLD vs POSITIVE AND NEGATIVE SUPPLY VOLTAGE
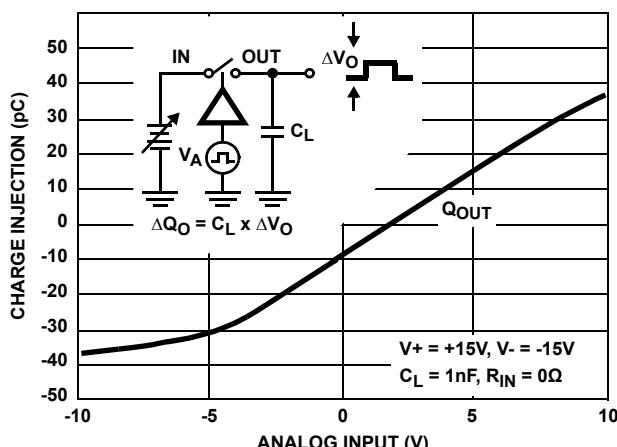


FIGURE 24. CHARGE INJECTION vs ANALOG INPUT
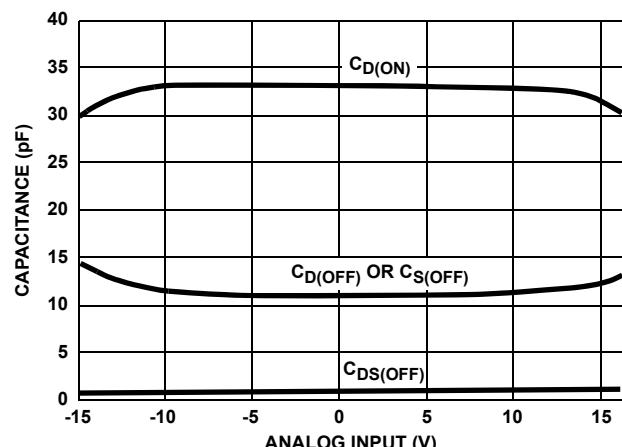


FIGURE 25. CAPACITANCE vs ANALOG INPUT
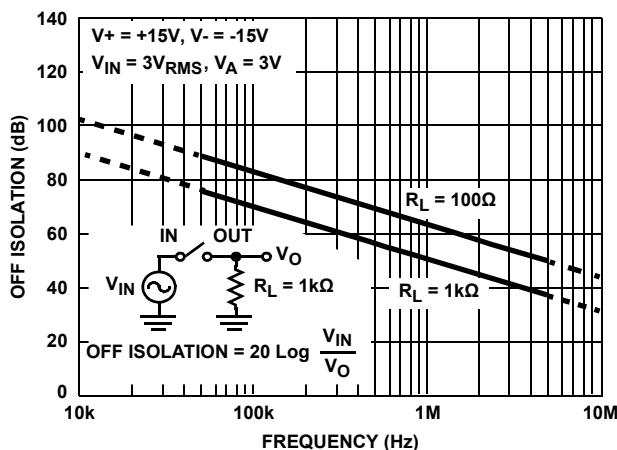


FIGURE 26. OFF ISOLATION vs FREQUENCY
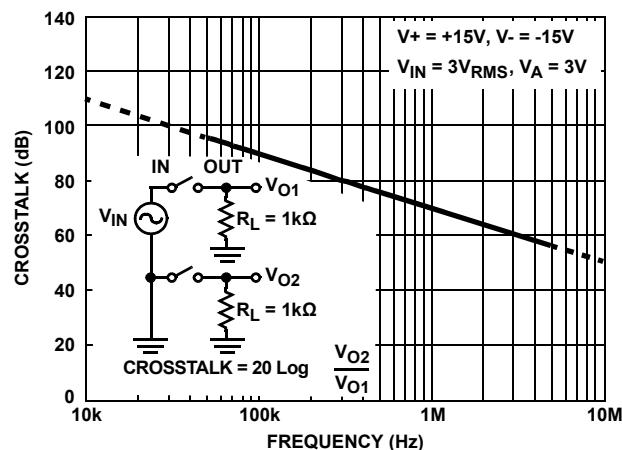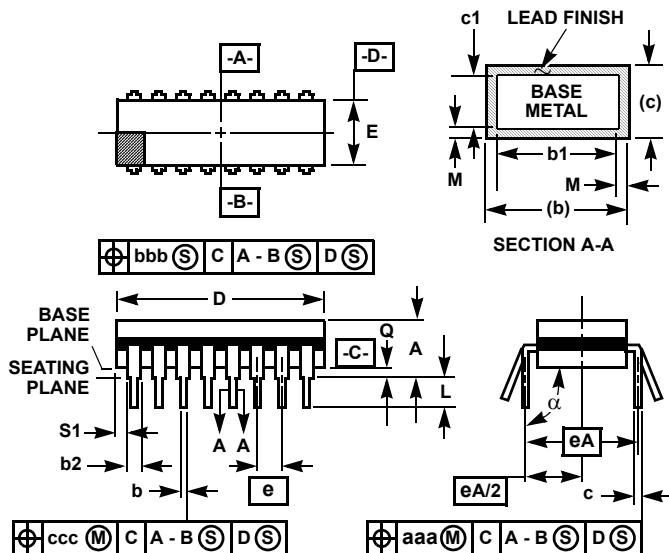


FIGURE 27. CROSSTALK vs FREQUENCY

## *Ceramic Dual-In-Line Frit Seal Packages (CERDIP)*



SECTION A-A

**F16.3** MIL-STD-1835 GDIP1-T16 (D-2, CONFIGURATION A)
**16 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE**

| SYMBOL | INCHES | | MILLIMETERS | | NOTES |
|--------|--------|--------|-------------|--------|-------|
| | MIN | MAX | MIN | MAX | |
| A | - | 0.200 | - | 5.08 | - |
| b | 0.014 | 0.026 | 0.36 | 0.66 | 2 |
| b1 | 0.014 | 0.023 | 0.36 | 0.58 | 3 |
| b2 | 0.045 | 0.065 | 1.14 | 1.65 | - |
| b3 | 0.023 | 0.045 | 0.58 | 1.14 | 4 |
| c | 0.008 | 0.018 | 0.20 | 0.46 | 2 |
| c1 | 0.008 | 0.015 | 0.20 | 0.38 | 3 |
| D | - | 0.840 | - | 21.34 | 5 |
| E | 0.220 | 0.310 | 5.59 | 7.87 | 5 |
| e | 0.100 BSC | | 2.54 BSC | | - |
| eA | 0.300 BSC | | 7.62 BSC | | - |
| eA/2 | 0.150 BSC | | 3.81 BSC | | - |
| L | 0.125 | 0.200 | 3.18 | 5.08 | - |
| Q | 0.015 | 0.060 | 0.38 | 1.52 | 6 |
| S1 | 0.005 | - | 0.13 | - | 7 |
| $\alpha$ | $90^o$ | $105^o$ | $90^o$ | $105^o$ | - |
| aaa | - | 0.015 | - | 0.38 | - |
| bbb | - | 0.030 | - | 0.76 | - |
| ccc | - | 0.010 | - | 0.25 | - |
| M | - | 0.0015 | - | 0.038 | 2, 3 |
| N | 16 | | 16 | | 8 |

Rev. 0 4/94

NOTES:

1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.

2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.

3. Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.

4. Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.

5. This dimension allows for off-center lid, meniscus, and glass overrun.

6. Dimension Q shall be measured from the seating plane to the base plane.

7. Measure dimension S1 at all four corners.

8. N is the maximum number of terminal positions.

9. Dimensioning and tolerancing per ANSI Y14.5M - 1982.

10. Controlling dimension: INCH.

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PI5A392AQE  MAX4744HELB+T  PI5A4157ZUEX  MC74HC4067ADTR2G  PI5A4158ZAEX  PI5A3166TAEX  MAX4901EBL+T
MAX14510EEVB+T  PI3A3899ZTEX  MAX4996ETG+T  MAX4889AETO+T  MAX14508EEVB+T  MAX4701ETE+T  MAX4996LETG+T
NLX2G66FCTAG  TMUX136RSER  HV2605FG-G  DG302BDJ-E3  ADG741BKSZ-REEL  ADG742BKSZ5-REEL7  PI5A100WE